

GL112□9 Series

12-Dots Array LED

■ Model No.

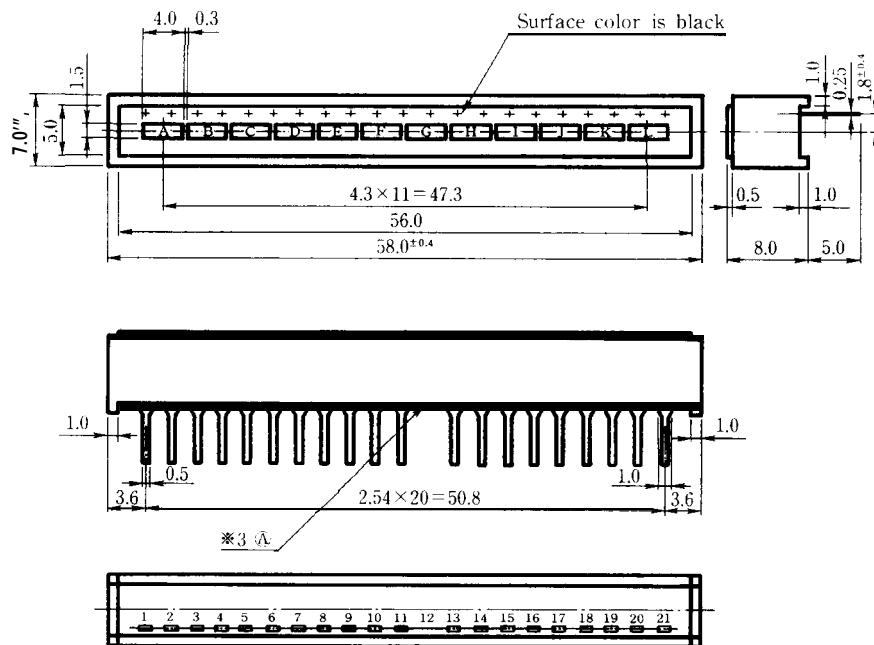
GL112R9 Red GaP
 GL112H9 Yellow GaAsP/GaP

■ Features

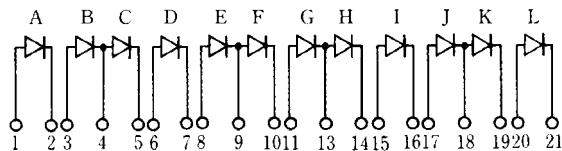
1. Radiation shape per dots $1.5 \times 4.0\text{mm}$
2. Outline dimensions $7.0 \times 58.0\text{mm}$
3. 12 dots case mold type

■ Outline Dimensions

(Unit: mm)



Internal connection diagram

Unspecified tolerance $\pm 0.38\text{mm}$

GL112□9**■ Absolute Maximum Ratings** ^{*1}

(Ta = 25°C)

Parameter	Symbol	GL112R9	GL112H9				Unit
Power dissipation	P	25	50				mW
Continuous forward current	I _F	10	20				mA
*2 Peak forward current	I _{FM}	50	50				mA
Derating factor	DC	—	0.18	0.36			m A/°C
	Pulse	—	0.91	0.91			m A/°C
Reverse voltage	V _R	5	5				v
Operating temperature	T _{opr}	-20 to +70					°C
Storage temperature	T _{stg}	-30 to +80					°C
*3 Soldering temperature	T _{sol}	260 (within 5 seconds)					'C

※1 Per dot

※2 Duty ratio = 1/10, Pulse width = 0.1ms

※3 At the position of 2.6 mm from ④ level of outline dimensions

GL1 12R9(Red)

■ Electro-optical Characteristics ^{*1}

(Ta=25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V_F	GL112R9	$I_F = 5\text{mA}$	—	1.9	2.5	V
*4 Luminous intensity	I_V	GL112R9	$I_F = 5\text{mA}$	0.15	0.3	—	mcd
Peak emission wavelength	λ_p	GL112R9	$I_F = 5\text{mA}$	695	—	—	nm
Spectrum radiation bandwidth	$\Delta \lambda$	GL112R9	$I_F = 5\text{mA}$	100	—	—	nm
Reverse current	I_R	GL112R9	$V_R = 4\text{V}$	—	—	10	μA
Response frequency	f_c	GL112R9	—	—	4	—	MHz

*1 Per dot

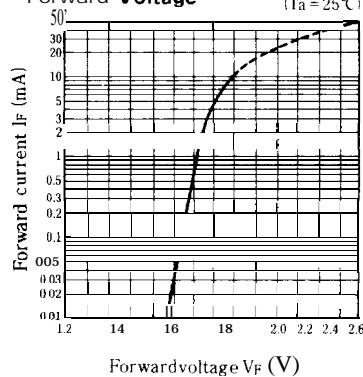
*4 Tolerance: $\pm 30\%$

■ Characteristics Diagrams

Forward Current vs.

Forward Voltage

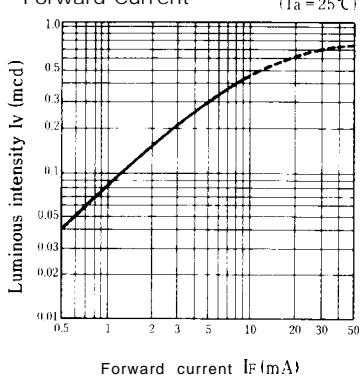
(Ta = 25°C)



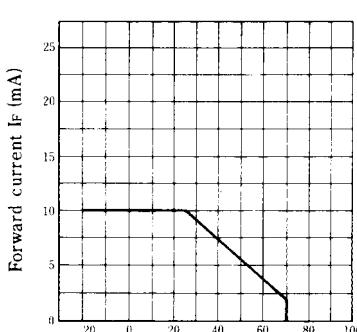
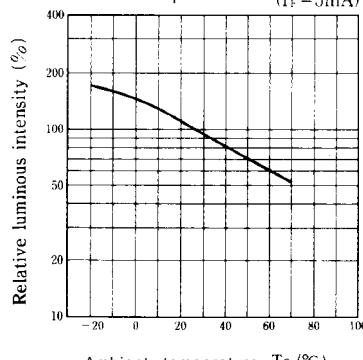
Luminous Intensity vs.

Forward Current

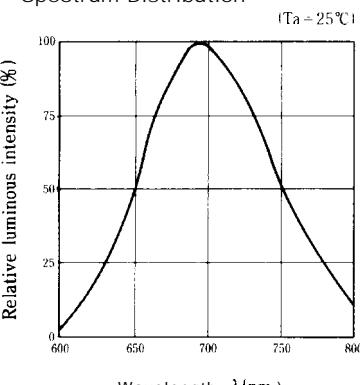
(Ta = 25°C)



Forward Current Derating Curve

Relative Luminous Intensity vs. Ambient Temperature ($I_F = 5\text{mA}$)

Spectrum Distribution



GL1 12H9(Yellow)

■ Electro-optical Characteristics ^{*1}

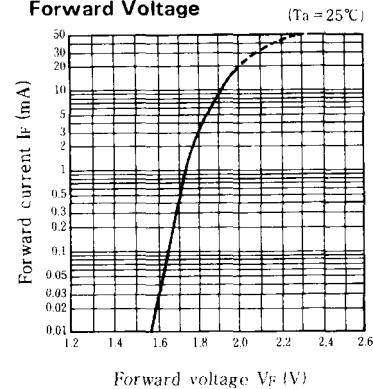
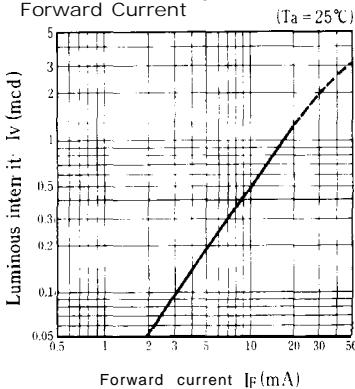
(Ta = 25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL112H9	I _F = 10mA	—	1.9	2.5	V
*4 Luminous intensity	I _V	GL112H9	I _F = 10mA	0.2	0.5	—	mcd
Peak emission wavelength	λ_p	GL112H9	I _F = 10mA	—	585	—	nm
Spectrum radiation bandwidth	$\Delta\lambda$	GL112H9	I _F = 10mA	—	30	—	nm
Reverse current	I _R	GL112H9	V _R = 4V	—	—	10	μA
Response frequency	f _C	GL112H9	—	—	4	—	MHz

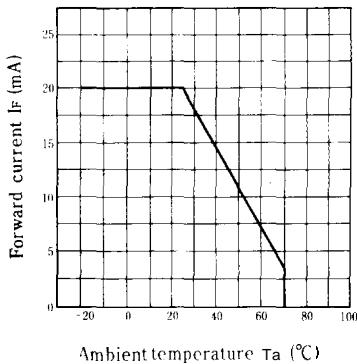
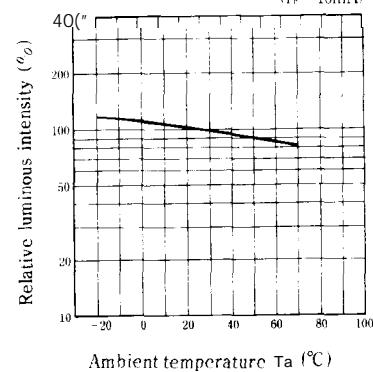
*1 Per dot

*4 Tolerance: $\pm 30\%$

■ Characteristics Diagrams

Forward Current vs.
Forward VoltageLuminous Intensity vs.
Forward Current

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature

Spectrum Distribution

